Ref #	Hits	Search Query	DBs	Default Operat or	Plural s	Time Stamp
Li	279945	light near5 emit\$4	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:10
L2	25837	1 and (ITO (indium near5 tin near5 oxide))	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:10
L3	11297	2 and bond\$3	US-PGPU B; USPAT; USOCR	OR	ON	-2005/10/15 18:11
L4	6038	3 and ("GaAs" "GaP")	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:11
L6	463	4 and (cladding "AlGaInP")	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:11
L7	269232	light near5 emit\$4	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/15 18:08
18	4364	7 and (ITO (indium near5 tin near5 oxide))	EPO; JPO; DERWENT ; IBM TDB	OR ·	ON ::	2005/10/15 18:08
L9	127	8 and bond\$3	EPO; JPO; DERWENT	OR	ON	2005/10/15 18:08
L10	10	9 and ("GaAs" "GaP")	IBM_TDB EPO; JPO; DERWENT	OR	. T	2005/10/15 18:09
a .			IBM_TDB		High with the	
L11	400724	diode	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:10
L12	21130	11 and (ITO (indium near5 tin near5 oxide))	US-PGPU B; USPAT; USOCR	OR .	ON	2005/10/15 18:10
L13	7813	12 and bond\$3	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:11

L14	4491	13 and ("GaAs" "GaP")	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:11
L15	444	14 and (cladding "AlGaInP")	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/15 18:11